# **VHF/UHF Tuner-IC**

### Description

This tuner IC requires a power supply of 12 V and performs the function of two separate oscillators and

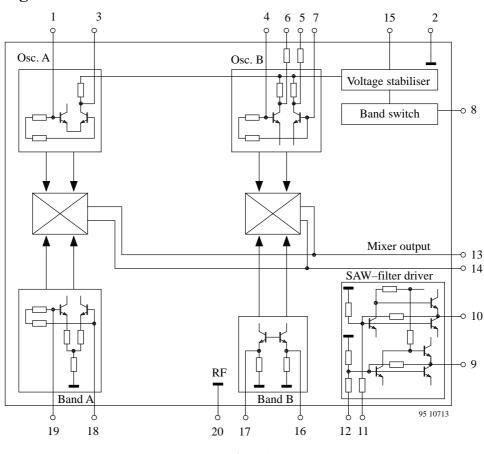
#### Features

- Frequency range from 48 to 860 MHz
- Band A: balanced high impedance mixer input and amplitude controlled oscillator
- Band B: balanced low impedance mixer input and symmetrical oscillator

#### **Block Diagram**

mixers, SAW-filter driver and dual state band switch.

- SAW filter driver with low impedance output
- Voltage regulator for stable operating characteristics
- ESD protection on all pins except oscillator pins and RF-inputs



#### Figure 1.

### **Ordering Information**

Extended Type Number	Package	Remarks		
U2320B-FLG3	SO20 plastic package	Taped and reeled		

# U2320B

## **Pin Description**

GND (RF) 1		20 Osc A, base
RF in, A $2$		19 GND (common)
RF in, A $3$		18 Osc A, coll.
RF in, B 4		17 Osc B, base
RF in, B 5		16 Osc B, coll.
V <sub>S</sub> 6		15 Osc B, coll.
Mix.out 7		14 Osc B, base
Mix. out 8		13 Band sw.
SAWF, inp. 9		12 SAWF, out
SAWF, inp. 10	9612044	11 SAWF, out

Pin	Symbol	Function
1	Osc A, base	Oscillator band A, base
2	GND	Ground, common
	(common)	
3	Osc A, coll.	Oscillator band A, collector
4, 7	Osc B, base	Oscillator band B, bases
5,6	Osc B, coll.	Oscillator band B, collectors
8	Band sw.	Dual-state band switch
9, 10	SAWF, out	SAW filter driver outputs
11, 12	SAWF, inp.	SAW filter driver input
13, 14	Mix, out	Mixer outputs, open collector
15	Vs	Supply voltage V <sub>s</sub>
16, 17	RF in, B	RF inputs, band B
18, 19	RF in, A	RF inputs, band A
20	GND (RF)	Ground, RF part

# **Absolute Maximum Ratings**

All voltages are referred to GND, Pin 2

Parameters	Test Conditions / Pins	Symbol	Min.	Тур.	Max.	Unit
Supply voltage	Pin 15	Vs			13,.5	V
RF inputs	Pin 16-19				5.0	V
IF outputs	Pin 13-14				13.5	V
Dual-state switch voltage	Pin 8	ViDSW			13.5	V
Junction temperature		Τ <sub>i</sub>			150	°C
Storage temperature		T <sub>stg</sub>	-40		150	°C

# **Operating Range**

All voltages are referred to GND, Pin 2

Parameters	Test Conditions / Pins	Symbol	Min.	Тур.	Max.	Unit
Supply voltage	Pin 13-15	Vs	10.8	12	13.2	V
Ambient temperature	With heat conductive glue	T <sub>amb</sub>	-25		75	°C

## **Thermal Resistance**

Parameters	Test Conditions / Pins	Symbol	Min.	Тур.	Max.	Unit
Junction ambient	Test conditions page 4 Package soldered to PCB	R <sub>thJA</sub>		90		K/W

## **Electrical Characteristics**

Test conditions (unless otherwise specified): Vs = 12 V,  $T_{amb} = 25$  °C, reference point Pin 2, referred to test circuit page 5.

Parameters	Test Conditions / Pins		Symbol	Min.	Тур.	Max.	Unit
Supply voltage		Pin 13-15	Vs	10.8	12.0	13.2	V
Supply current		Pin 13-15	IS		42	50	mA
Band switch							
Voltage band A		Pin 8	VSWA	0	0	1.0	V
Voltage band B		Pin 8	VSWB	3.4	4.0	5.0	V
Switching current	VSW = 5 V	Pin 8	ISW			100	μΑ
SAW filter driver	fi = 36 MHz						
Input impedance		Pin 11, 12	ZiSAW		450		Ω
Output impedance		Pin 9, 10	ZoSAW		70		Ω
Voltage gain	$11, 12 \rightarrow 9, 10$		GvSAW		19		dB
Band A (note 1)							
Input frequency range		Pin18	fiA	48		470	MHz
Input impedance	Figure 4	Pin18	S11A				
Gain (note 4)		I/P to O/P	GA		30		dB
Noise figure DSB (note 2)	fiA = 50 MHz fiA = 150 MHz	I/P to O/P	NF		11.5 12		dB dB
Input level for (note 3):	Each carrier				12		uD
IM3 (Interm. of 3rd order)	fiA = 71 MHz	I/P	ViA		-22		dBm
IM2 (Interm. of 2nd order)	fiA = 71 MHz	I/P	ViA		-22		dBm
Band B (note 1)							
Input frequency range		Pin 16, 17	fiB	470		860	MHz
Input impedance	Figure 4	Pin 16, 17	S11B				
Gain (note 4)		I/P to O/P	GB		34		dB
Noise figure DSB (note 2)	fiB = 500 MHz fiB = 800 MHz	I/P to O/P	NF		10.5 11.5		dB dB
Input level for IM3	Each carrier				11.0		
(Interm. of 3rd order, note 3)	fiB = 600  MHz	I/P	ViB		-27		dBm

#### Notes

<sup>1)</sup> The RF input B is symmetrical driven by means of a hybrid for  $180^{\circ}$  phase shifting, consequently the source impedance is 100  $\Omega$ . All other impedance for RF tests is 50  $\Omega$ .

- <sup>2)</sup> The noise figure (NF) is the value for double-side-band measurement.
- <sup>3)</sup> The intermodulation test (2-carrier-method) which is made on IF-centre is in reference to a signal-to-IM ratio of 60 dB.
- <sup>4</sup>) Gain is the ratio of the voltage at the primary coil of L5 to the available voltage at the input.

## **Test and Principle Application Circuit**

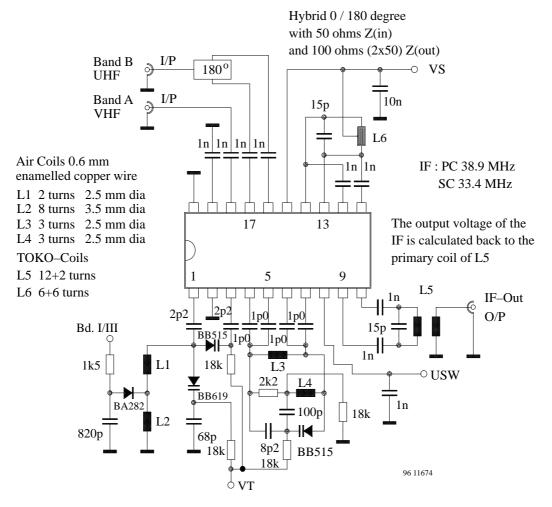
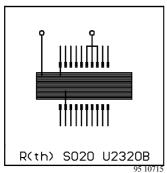


Figure 2. Test and principle application circuit

Note: All component values must be determined application specific. For more detailed information pls. request the application note "Semiconductors for TV-Tuners and The New EasyLink Concept".

#### PCB for the R<sub>thJA</sub>-Measurement



40 mm x 40 mm x 1.5 mm.

35 µm one-sided Cu-coated PCB,

Figure 3. PCB for the RthJA-measurement



#### **Input Impedance Mixer Band A (S11A) and B (S11B)**

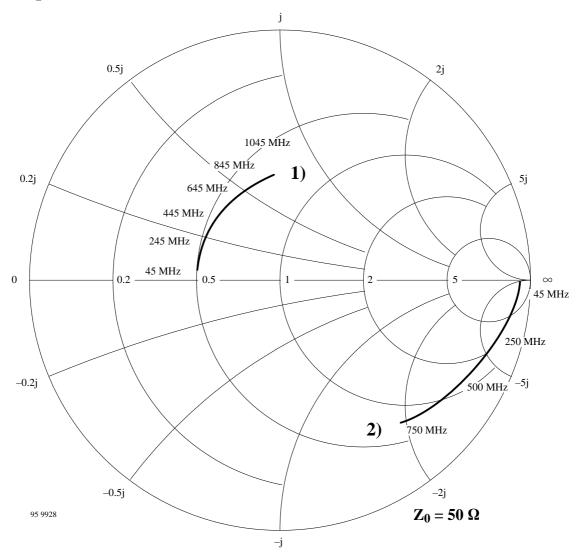


Figure 4. Input impedance mixer band A (S11A), and B (S11B)

#### 1) VHF-Low

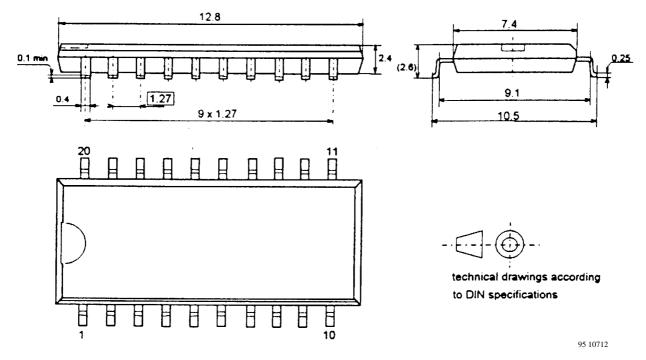
Normalized to 50  $\Omega$ , measuring range 45 MHz to 750 MHz.

#### 2) VHF-High and UHF

Normalized to 50  $\Omega$ , measuring range 45 MHz to 1045 MHz. Both inputs are driven symmetrical. The output impedance of the hybrid is 100  $\Omega$ , the measured levels are then calculated in reference to 50  $\Omega$ .

## **Package Dimensions**

Small outline plastic package, 20 pin-SO20 Dimensions in mm



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- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

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